

# Vacuum Soldering System for processing also for contaminating processes



VSS-450-300 Vacuum Solder System

## VSS-300, VSS-300-HV

- For substrate size up to 300 mm x 300 mm x 70 mm
- Ramp up rate up to 150 K/min
- SIMATIC® Controller with 7" touch panel
- Vacuum up to  $10^{-3}$  hPa (opt.  $10^{-6}$  hPa)
- Process gas line with Mass Flow Controller for Nitrogen
- Temperature up to 450 °C (opt. up to 600 °C)

### Application

Reflow Solder Processes with or without vacuum up to  $10^{-6}$  hPa. Easy profiling by using a SPS SIMATIC® Controller with WIN based software. Perfect lab tool and also for production on a low cost base. High production output. A remote control can be adjusted and the system can easily integrated into a production line.

- Reflow Solder Processes with flux
- Operation with inert gas, Oxygen, Forming gas, Formic Acid
- Lead and Lead-free SMT reflow
- Resistor paste firing

### Features

- Precise ramp up and fast ramp down rates
- Up to 4 gas lines (Mass Flow Controller)
- Heated by Infrared lamps
- 50 programs with 50 steps each
- Top and bottom heating (selection by Software)
- Small foot print
- 3 heating zones programmable

## VSS-300, VSS-300-HV

- Vacuum Solder System
- Programmable temperature profiles
- Record of process data
- Process in different gas atmospheres

### The VSS-300 Vacuum Process Oven

The VSS-300 Reflow Solder System is an excellent tool for various solder processes up to 300 mm diameter wafer or 300 mm x 300 mm substrate size and 75 mm height (Option: EH with 120 mm height).

Some examples for applications:

Laboratory furnace for all kind of developers implementing and researching new processes, prototype research, environmental research purposes and for small pre-series or series.

### Process Gases

The VSS-300 can be used with standard process gases, like Nitrogen, Oxygen, Forming Gas. The chamber is sealed and can easily be cleaned.

### Gas flow control

One gas line with Mass Flow Controller (MFC) for Nitrogen (5 nlm = norm liter per minute) is default, three more gas lines (Option: MFC) are possible.

### Vacuum

The system is vacuum capable of up to  $10^{-3}$  hPa (optionally up to  $10^{-6}$  hPa).

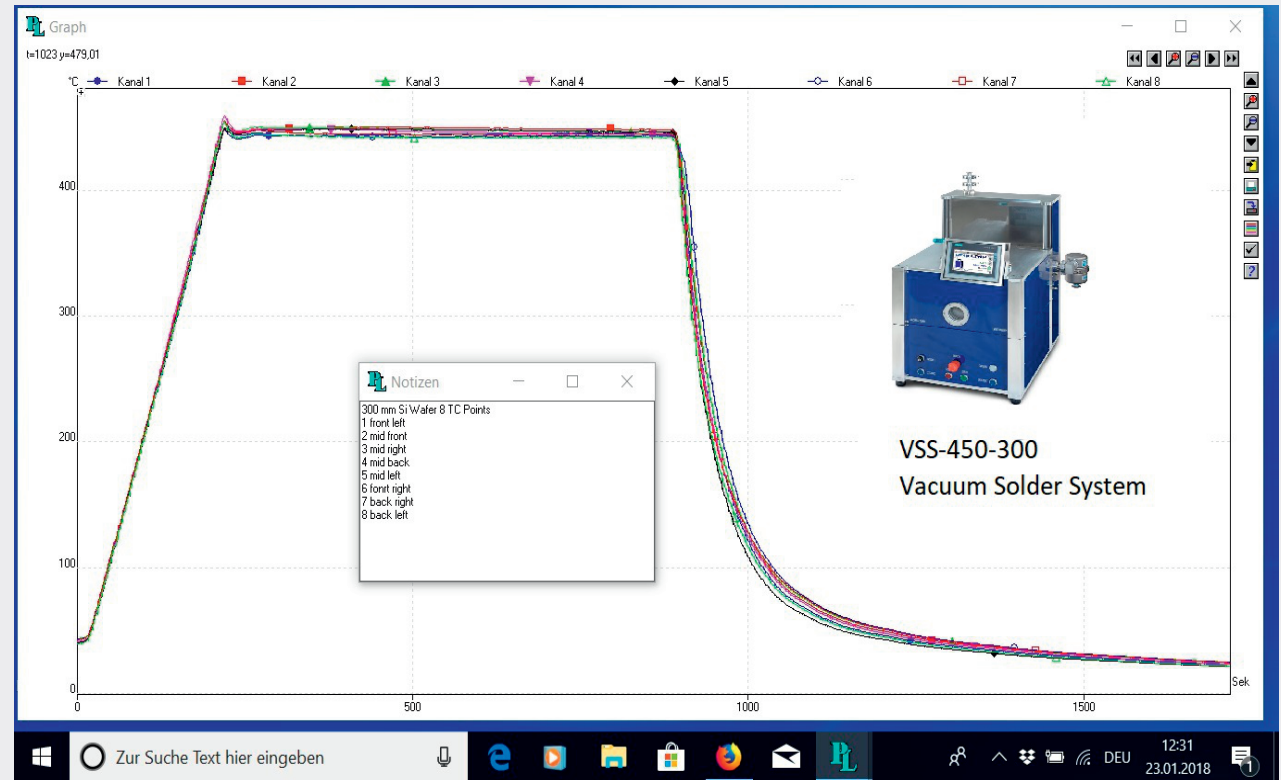
### Heating

The maximal achievable temperature is 450 °C (opt. 650 °C). Key features are precisely controlled fast ramp-up (150 K/min) and excellent ramp-down rates (depend on temperature and loading).

### Temperature distribution

The VSS-300 allows an excellent temperature distribution and homogeneity. Optionally a graphite susceptor can be inserted on the quartz bottom plate.

VSS-300 Example for a standard temperature profile with VSS-450-300



### Programming

The VSS-300 is controlled by SPS SIMATIC® controller. A 7" touch panel allows a very comfortable programming and control of the process. There can be saved up to 50 programs with 50 steps each (unlimited programs can be down- and uploaded from an external data storage).

### Process control

The software allows the permanent monitoring, readout and analysis of

- temperature
- process gas flow
- cooling water level status
- pressure value and status

### Cooling process

The hot plate is active cooled with homogenous cooling from both sides.

### Others

An interlock function as well as an Emergency-OFF-Button (EMO) are default.

### Special

This oven can also be integrated into a production line. The chamber open/close is realized by push button operation.



## No. Options:

### Additional process gas lines:

1	VSS-MFC-Ar	Additional process gas line for Argon (Ar) gas controlled by Mass Flow Controller
2	VSS-MFC-O2	Additional process gas line for Oxygen (O <sub>2</sub> ) gas controlled by Mass Flow Controller
3	VSS-MFC-FG	Additional process gas line for Forming Gas (max. 10 % H <sub>2</sub> /N <sub>2</sub> ) gas controlled by Mass Flow Controller

### Formic acid module and trap:

4	FA II	Upgrade with integrated formic acid module with individually controlled process gas line
5	FA III	Upgrade with integrated formic acid module (process gas line shared with base VSS system)
6	FA IV	Formic acid module with separate gas line and automatic refilling
7	FA-T	Trap for formic acid vapors
8	FA-T-2	Double Trap for formic acid

### Flux options:

9	VSS-FluxHeat	Heated cover for sue with flux for avoiding condensating flux
10	VSS-FT	Flux trap
11	VSS-FT-2	Flux trap

### Height and lift pins options:

12	VSS-EH	Extended chamber height up to 120 mm, including 65 mm diameter viewing window
13	VSS-LiftPins	Upgrade with Lift pins for lifting up of single wafer (150 mm, 200 mm or 300 mm diameter)

### Hydrogen gas options

14	H2	Hydrogen option for use of pure hydrogen gas (100% H <sub>2</sub> )
15	H2S	Safety hood

### Additional thermocouples:

16	TC I	Upgrade with additional (flexible) thermocouple (not connected to process control, for external data logging)
17	TC II	additional thermocouple to measure on device (plugged in chamber); for external measurement tool (max. 4 pcs)

### Vacuum options (not including vacuum pumps):

18	VAC I	Vacuum basic up to 3 hPa incl. vacuum sensor and valve
19	VAC II	Vacuum comfort up to 10 <sup>-3</sup> hPa incl. vacuum sensor and valve

### Interfaces:

20	VSS-RC	Remote control of top cover opening and closing, including connection to safety of external cabinet
21	VSS-SI	Serial interface between VSS system and external PC using USB 2.0 port and through USB 2.0 cable

### Measurement options:

22	MM	Moisture measurement
23	Ox	Atmospheric oxygen analyser

### Other options:

24	CAB	Cabinet with integrated Universal Heat Exchanger (UHE)
25	PT	Upgrade with 3 colors pat light
26	VSS-QP	Additional quartz glass plate at top
27	VSS-HT	Extension of max temperature to 600 °C
	VSS-TH	Top heat (power x2), add. lamp field in the top
	VSS-ExOH	Extended opening from 200 mm to 300 mm

### Accessories (vacuum pumps, chiller):

28	MP	Membrane/diaphragm pump (not chemically resistant)
29	MPC	Chemically resistant membrane/diaphragm pump
30	RVP	Rotary vane pump for vacuum up to 10exp. <sup>-3</sup> with oil filter
31	WC III	Closed loop water cooling system
32	UHE	Universal Heat exchanger (as alternative to WC-III, requires cooling water for its primary side)

## Specification

<b>Max. part size</b>	300 mm dia. or 300 mm x 300 mm
<b>Chamber material</b>	Aluminium chamber (chamber area: 350 mm x 350 mm) inclusive quartz fram
<b>Chamber height</b>	75 mm (optional: 120 mm)
<b>Vacuum capability</b>	Up to 10 <sup>-3</sup> hPa (optional up to 10 <sup>-6</sup> hPa)
<b>Temperature max.</b>	450 °C (higher temp. on request)
<b>Temp. uniformity</b>	≤ 1 % of set temperature (on a 200 mm wafer) (e.g. ± 3K @ 300 °C)
<b>Heating</b>	Bottom Heating: Infrared lamps cross aligned (18 kW)
<b>Ramp up rate</b>	<b>150K/min</b>
<b>Ramp down rate</b>	T = 450 °C > 200 °C: 90 K/min, T = 200 °C > 100 °C: 60 K/min
<b>Flow Controller</b>	One Mass Flow Controller for 5 nlm (=norm liter per minute) as default, up to 3 more Mass Flow Controllers are available as option
<b>Controller</b>	SIMATIC® controller 50 programs with 50 steps each
<b>Chamber cooling</b>	By external water cooling system
<b>Substrate Cooling</b>	By Nitrogen Gas

## Technical Data

<b>Dimension oven</b>	540 mm x 690 mm x 890 mm (W x D x H)
<b>Weight</b>	120 kg
<b>Electrical connection</b>	400/230 V, 18 kW

